# PACKAGE DIMENSIONS INCH [mm] 



TO-5 HERMETIC CAN PACKAGE
ACTIVE AREA $=4.48 \mathrm{~mm}^{2}$

## FEATURES

- Lownoise
- U.V. enhanced
- High shunt resistance
- U.V window


## DESCRIPTION

The PDU-V105 is a silicon, PIN planar diffused, U.V. enhanced photodiode. Ideal for low noise photovoltaic applications.
Packaged in a hermetic TO-5 metal can with a flat U.V. transmitting window.

## APPLICATIONS

- Spectrometers
- Fluorescent analysers
- U.V. meters
- Colorimeters


## ABSOLUTE MAXIMUM RATING (TA=25 ${ }^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | PARAMETER | MIN | MAX | UNITS |
| :---: | :--- | :---: | :---: | :---: |
| $\mathrm{V}_{\text {BR }}$ | Reverse Voltage |  | 75 | V |
| $\mathrm{~T}_{\text {STG }}$ | Storage Temperature | -55 | +150 | ${ }^{\circ} \mathrm{C}$ |
| T o | Operating Temperature Range | -40 | +125 | ${ }^{\circ} \mathrm{C}$ |
| Ts | Soldering Temperature* |  | +240 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{I}_{\mathrm{L}}$ | Light Current |  | 500 | mA |

*1/16 inch from case for 3 secs max

## SPECTRALRESPONSE

ELECTRO-OPTICAL CHARACTERISTICS (TA $=25^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | CHARACTERISTIC | TESTCONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :--- | :--- | :---: | :---: | :---: | :---: |
| Isc | Short Circuit Current | $\mathrm{H}=100 \mathrm{fc}, 2850 \mathrm{~K}$ | 30 | 50 |  | $\mu \mathrm{~A}$ |
| ID | Dark Current | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{mV}$ |  | 2 | 5 | pA |
| Rsh | Shunt Resistance | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{mV}$ | 2 | 5 |  | $\mathrm{G} \Omega$ |
| TC RsH | RSH Temp. Coefficient | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{mV}$ |  | -8 |  | $\% /{ }^{\circ} \mathrm{C}$ |
| $\mathrm{C} J$ | Junction Capacitance | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=0 \mathrm{~V}^{* *}$ |  | 500 |  | pF |
| $\lambda$ range | Spectral Application Range | Spot Scan | 190 |  | 1100 | nm |
| R | Responsivity | $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}, \lambda=254 \mathrm{~nm}$ | .12 | .18 |  | $\mathrm{~A} / \mathrm{W}$ |
| $\mathrm{V}_{\text {BR }}$ | Breakdown Voltage | $\mathrm{I}=10 \mu \mathrm{~A}$ | 5 | 10 |  | V |
| NEP | Noise Equivalent Power | $\mathrm{V}_{\mathrm{R}}=10 \mathrm{mV} @$ Peak |  | $.5 \times 10^{-14}$ |  | $\mathrm{~W} / \sqrt{\mathrm{Hz}}$ |
| tr | Response Time | $\mathrm{RL}=1 \mathrm{~K} \Omega \mathrm{~V}_{\mathrm{R}}=0 \mathrm{~V}$ |  | 500 |  | nS |

Information in this technical datasheet is believed to be correctand reliable. However, noresponsibility is assumed for possible inaccuracies oromission. Specifications are subject to change without notice.**f $=1 \mathrm{MHz}$
[FORM NO. 100-PDU-V105 REV A]

